## ELECTRONIC SUPPLEMENTARY MATERIAL

Boron elemental and isotopic determination via the BF diatomic molecule using high-resolution continuum source graphite furnace molecular absorption spectrometry

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## Theoretical estimation of isotopic shifts

The theoretical isotopic shift can be derived from the equation available in the classic book of Herzberg ${ }^{1}$ and reproduced below:

$$
\begin{aligned}
\Delta v=(1-\rho) & {\left[\omega_{e}^{\prime}\left(v^{\prime}+\frac{1}{2}\right)-\omega_{e}^{\prime \prime}\left(v^{\prime \prime}+\frac{1}{2}\right)\right] } \\
& -\left(1-\rho^{2}\right)\left[\omega_{e}^{\prime} x_{e}^{\prime}\left(v^{\prime}+\frac{1}{2}\right)^{2}-\omega_{e}^{\prime \prime} x_{e}^{\prime \prime}\left(v^{\prime \prime}+\frac{1}{2}\right)^{2}\right] \\
& +\left(1-\rho^{3}\right)\left[\omega_{e}^{\prime} y_{e}^{\prime}\left(v^{\prime}+\frac{1}{2}\right)^{3}-\omega_{e}^{\prime \prime} y_{e}^{\prime \prime}\left(v^{\prime \prime}+\frac{1}{2}\right)^{3}\right]
\end{aligned}
$$

where $\Delta v$ is the isotopic shift in $\mathrm{cm}^{-1}, v$ is the vibrational quantum number, $\omega_{e}$ is the harmonic frequency, $\omega_{e} x_{e}$ and $\omega_{e} y_{e}$ are the first and second anharmonic constants, respectively; $\rho=\left(\mu / \mu^{i}\right)^{1 / 2}$, where $\mu$ is the reduced mass of the molecule and i corresponds to the heavier isotope. The number of apostrophes denotes the electronic levels (two for the lower one, and one for the upper one) involved in the electronic transition.

## References

1 G. Herzberg, Molecular Spectra and Molecule Structure. I. Spectra of Diatomic Molecules, D. Van Nostrand Company, INC., Princeton, 2nd edn., 1950.

Table S1. Sequence for coating the graphite platform of a Graphite Furnace (GF) with W

1. Pipet $50 \mu \mathrm{~L}$ (integrated platform in GF for liquid samples), or $30 \mu \mathrm{~L}$ (platform for solid sample introduction) of a $1000 \mathrm{mg} \mathrm{L}^{-1} \mathrm{~W}$ standard solution onto the platform.
2. Run the following temperature program.

| Step | Temperature $\left({ }^{\circ} \mathrm{C}\right)$ | Ramp $\left({ }^{\circ} \mathrm{C} \mathrm{s} \mathrm{s}^{-1}\right)$ | Hold $(\mathbf{s})$ | Ar gas flow <br> $\left(\mathrm{L} \mathrm{min}^{-1}\right)$ |
| :--- | :--- | :--- | :--- | :--- |
| Drying | 120 | 24 | 25 | 2 |
| Drying | 150 | 15 | 60 | 2 |
| Pyrolisis | 600 | 30 | 10 | 2 |
| Gas | 600 | 0 | 5 | 2 |
| Adaptation Atomization 1000 100 15 | 2 |  |  |  |

3. Repeat steps 1 and 2 either 3 times (integrated platform in GF for liquid samples) or 6 times (platform for solid sample introduction)
4. Pipet $50 \mu \mathrm{~L}$ (integrated platform in GF for liquid samples), or $25 \mu \mathrm{~L}$ (platform for solid sample introduction) of a $1000 \mathrm{mg} \mathrm{L}^{-1} \mathrm{~W}$ standard solution onto the platform.
5. Run the following temperature program, once for the integrated platform in GF for liquid samples and twice for the platform for solid sample introduction.

| Step | Temperature ( ${ }^{\circ} \mathrm{C}$ ) | Ramp ( ${ }^{\circ} \mathrm{C} \mathrm{s}{ }^{-1}$ ) | Hold (s) | Ar gas flow ( $\mathrm{L} \mathrm{min}^{-1}$ ) |
| :---: | :---: | :---: | :---: | :---: |
| Drying | 120 | 24 | 25 | 2 |
| Drying | 150 | 3 | 60 | 2 |
| Pyrolisis | 600 | 18 | 10 | 2 |
| Gas <br> Adaptation | 600 | 0 | 5 | 2 |
| Atomization | 1000 | 40 | 15 | 2 |
| Clean | 1400 | 40 | 5 | 2 |
| Clean | 2000 | 200 | 2 | 2 |

6. Run the following temperature program four times:

| Step | Temperature $\left({ }^{\circ} \mathrm{C}\right)$ | Ramp $\left({ }^{\circ} \mathrm{C} \mathrm{s} \mathrm{s}^{\mathbf{- 1}}\right)$ | Hold $(\mathbf{s})$ | Ar gas flow <br> $\left(\mathrm{L}\right.$ min $\left.^{-1}\right)$ |
| :--- | :--- | :--- | :--- | :--- |
| Drying | 150 | 150 | 10 | 2 |
| Drying | 600 | 35 | 10 | 2 |
| Gas | 600 | 0 | 5 | 2 |
| Adaptation | 1100 | 50 | 5 | 2 |
| Atomization | 1400 | 30 | 10 | 2 |
| Clean | 1400 |  |  |  |

7. Run the following temperature program four times.

| Step | Temperature $\left({ }^{\circ} \mathrm{C}\right)$ | Ramp $\left({ }^{\circ} \mathbf{C ~ s ~ s}^{\mathbf{- 1})}\right.$ | Hold (s) | Ar gas flow <br> $\left(\mathrm{L} \mathbf{m i n}^{-1}\right)$ |
| :--- | :--- | :--- | :--- | :--- |
| Drying | 150 | 150 | 10 | 2 |
| Drying | 600 | 35 | 10 | 2 |
| Gas | 600 | 0 | 5 | 2 |
| Adaptation | 1100 | 50 | 5 | 2 |
| Atomization | 11400 | 30 | 10 | 2 |
| Clean | 1500 | 34 | 5 | 2 |
| Clean | 1600 | 100 | 1 | 2 |
| Clean | 1700 | 100 | 1 | 2 |
| Clean | 1800 | 100 | 1 | 2 |
| Clean | 180 | 100 | 1 | 2 |
| Clean | 1900 | 100 | 1 | 2 |
| Clean | 2000 |  |  |  |

Table S2. Software conditions introduced in the ContrAA 800G instrument to perform the temperature program included in Table 1 for gas-phase fluorinating agents.

| Step | Temperature $\left({ }^{\circ} \mathrm{C}\right)$ | Ramp ( ${ }^{\circ} \mathrm{C} \mathrm{s}{ }^{-1}$ ) | Hold (s) | Gas flow ( $\mathrm{L} \mathrm{min}^{-1}$ ) |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Ar | Ar/CH3F |
| Drying | 80 | 6 | 20 | MAX | STOP |
| Drying | 110 | 5 | 40 | MAX | STOP |
| Pyrolysis | 850 | 300 | 20 | MAX | STOP |
| Gas adaptation | 850 | 0 | 5 | STOP | MAX |
| Atomization | 850 | 0 | 5 | STOP | MAX |
| Cleaning | 2500 | 1800 | 7 | STOP | STOP |
| Cleaning | 2700 | 3000 | 5 | MAX | STOP |

Table S3. Theoretical ( $\Delta \lambda_{\text {calc }}$ ) and experimental ( $\Delta \lambda_{\exp }$ ) isotopic shifts for the BF molecule in the region $190-207 \mathrm{~nm}$. Theoretical shifts, $\Delta \lambda$ calc, were calculated using the equation available on page 162 from reference 23 , while experimental isotopic shifts were only included when detection in the ContrAA 800G was possible due to sensitivity constrictions.

Electronic transition: $\mathrm{x}^{1} \Sigma-\mathrm{A}^{1} \Pi$

| $\lambda^{\mathrm{a}} / \mathrm{nm}$ | $\lambda_{\text {exp }} / \mathrm{nm}$ | $v^{\prime}, v^{\prime \prime}$ | $\Delta \lambda_{\text {calc }} / \mathrm{pm}$ | $\Delta \lambda_{\exp } / \mathrm{pm}$ |
| :---: | :---: | :---: | :---: | :---: |
| 207.15 | n.d. | 1,3 | 338 | n.d. |
| 206.74 | n.d. | 0,2 | 333 | n.d. |
| 201.58 | n.d. | 1,2 | 184 | n.d. |
| 201.1 | 201.080 | 0,1 | 173 | 167 |
| 196.27 | n.d. | 1,1 | 25.4 | n.d. |
| 195.74 | 195.588 | 0,0 | 8.38 | n.d. |
| 191.10 | n.d. | 1,0 | 139 | n.d. |
| 186.78 | n.d. | 2,0 | 280 | n.d. |

